

Supporting Information

Interphase Formation Versus Fluoride-ion Insertion in Tunnel-Structured Transition Metal Antimonites

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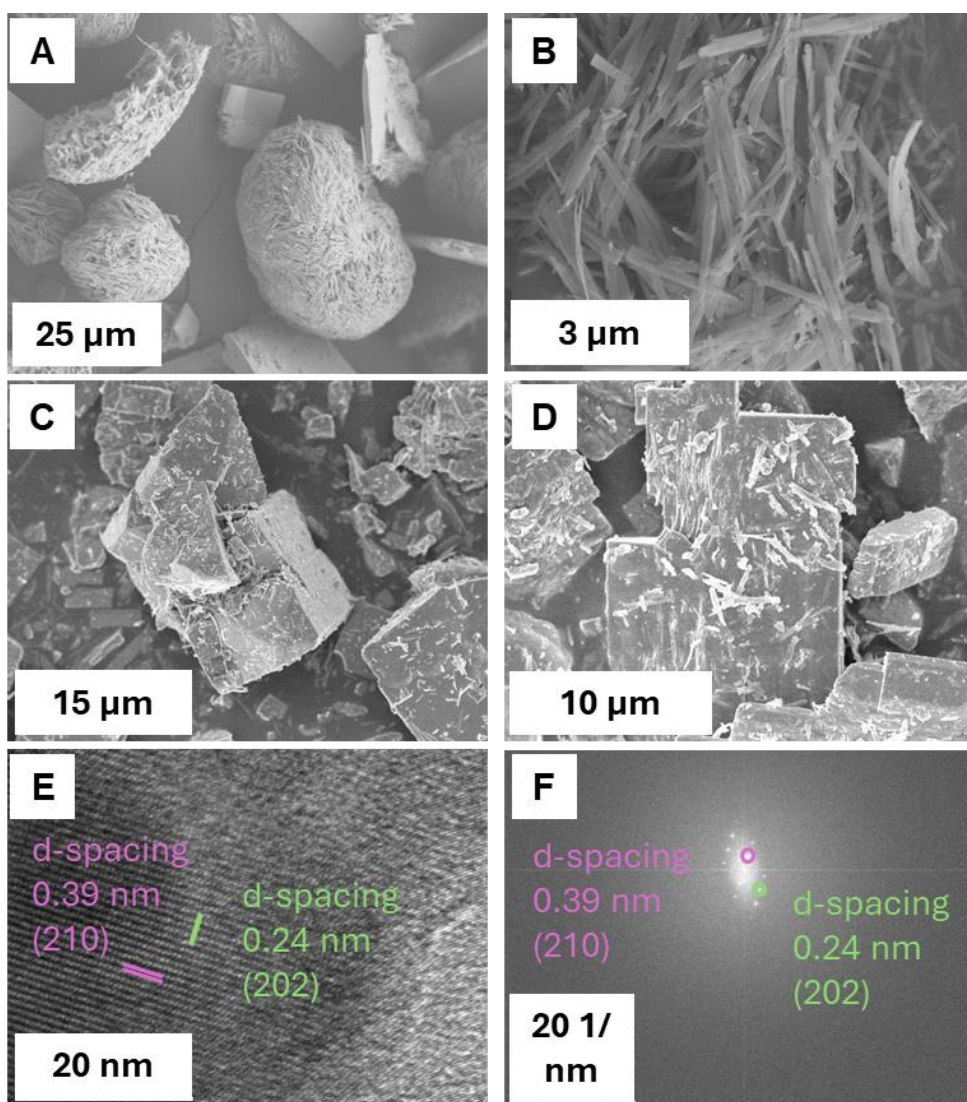


Figure S1. SEM Images of varying magnification for (A) MnSb_2O_4 synthesized hydrothermally at low magnification; (B) MnSb_2O_4 nanoparticles at higher magnification; (C) MnSb_2O_4 after hand grinding with a mortar and pestle; and (D) hand ground MnSb_2O_4 after treatment with a 1:1 molar ratio of XeF_2 in CH_3CN at 25 °C. (E) Lattice-resolved HRTEM image acquired for MnSb_2O_4 indicating the separation between (210) and (202) planes. (F) Indexed SAED pattern acquired for the as prepared MnSb_2O_4 indicating the (210) and (202) planes.

Table S1. Atom positions, fractional occupancies, and thermal parameters obtained from Rietveld refinement of the powder XRD pattern acquired for MnSb₂O₄. Refinement statistics and lattice parameters are included in the table header.

$a = b = 8.69572(10) \text{ \AA}, c = 6.00591(9) \text{ \AA}$ $\alpha = \beta = \gamma = 90^\circ; \text{Volume} = 454.140(10) \text{ \AA}^3$ $\chi^2 = 29.40(3); \text{wR} = 12.14(2) \%; \text{RF} = 3.29(8) \%$					
Atom Label	Site Multiplicity	x	y	z	U _{iso} (Å ²)
Mn	4	0	½	¼	0.0237(7)
Sb	8	0.17858(24)	0.16681(22)	0	0.0165(14)
O(1)	8	0.0961(12)	0.6574(13)	0	0.041(4)
O(2)	8	0.6866(7)	0.1866(7)	¼	0.036(4)

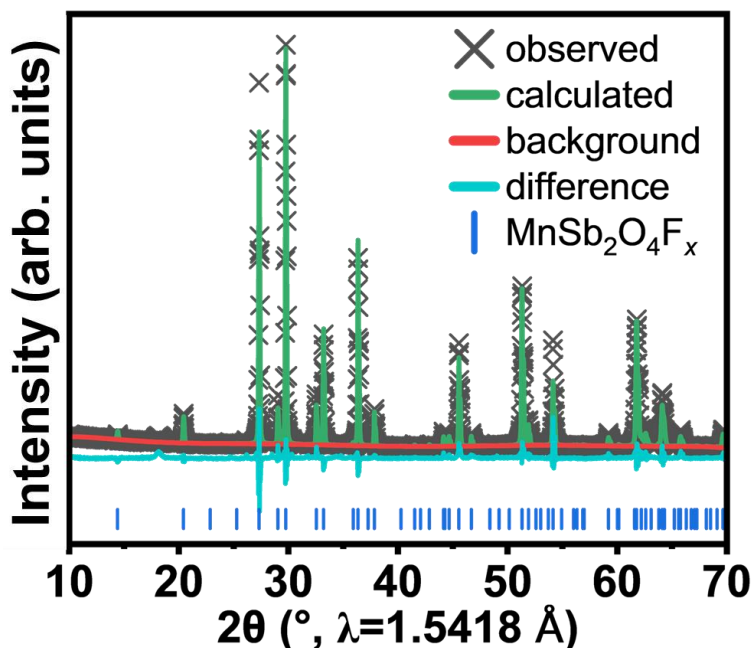


Figure S2. Rietveld refinement of powder X-ray diffraction data collected for MnSb₂O₄ after a 1 molar ratio treatment of XeF₂ in CH₃CN. Refinement statistics, lattice parameters, and atom positions for the refinements of the reacted material are shown in Table S2. This material experienced significant preferred orientation (March-Dollase Ratio of 0.527 for the unique axis 0 0 1).

Table S2. Atom positions, fractional occupancies, and thermal parameters obtained from Rietveld refinement of the powder XRD pattern acquired for MnSb₂O₄ after treatment with a 1:1 molar ratio of XeF₂ in CH₃CN. Refinement statistics and lattice parameters are included in the table header.

$a = b = 8.69736 \text{ \AA}, c = 6.00409 \text{ \AA}$ $\alpha = \beta = \gamma = 90^\circ; \text{Volume} = 454.173 \text{ \AA}^3$ $\chi^2 = 10.123; \text{R}_{\text{wp}} = 12.779\%; \text{RF} = 8.688\%$					
Atom Label	Site Multiplicity	x	y	z	U _{iso} *100
Mn	4	0.00	0.50	0.25	0.11(2)
Sb	8	0.1780(1)	0.1684(1)	0.00	0.01(0)
O(1)	8	0.0817(7)	0.6520(3)	0.00	0.22(5)
O(2)	8	0.6754(8)	0.1754(8)	0.25	2.84(1)
F	16	0.5273(5)	0.4961(7)	0.7404(2)	25

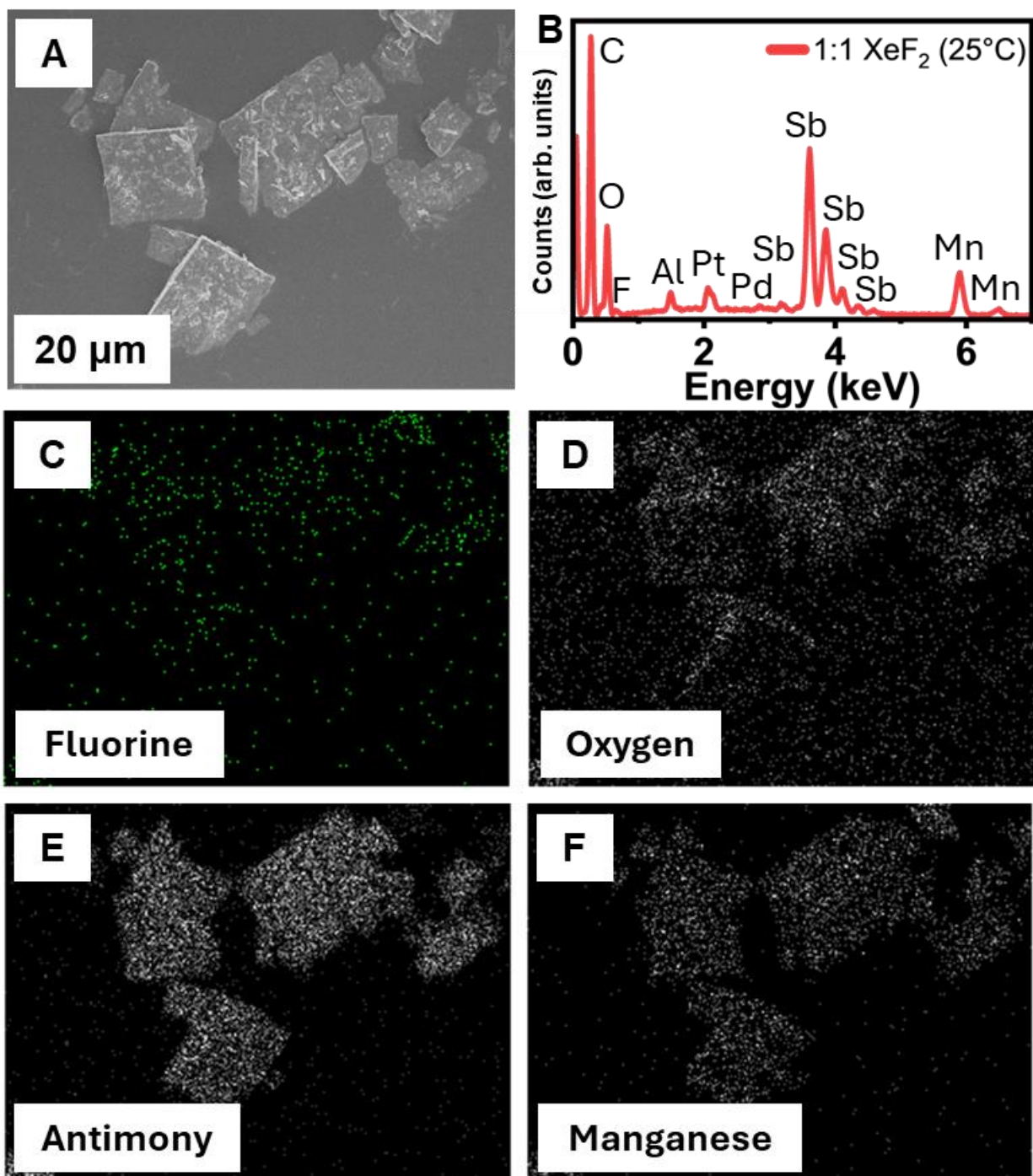


Figure S3. SEM-EDS images of 1:1 molar ratio of XeF_2 in CH_3CN at 25°C with (A) SEM image of as treated MnSb_2O_4 ; (B) EDS spectra; (C) fluorine elemental map; (D) oxygen elemental map; (E) antimony elemental map; and (G) manganese elemental map.

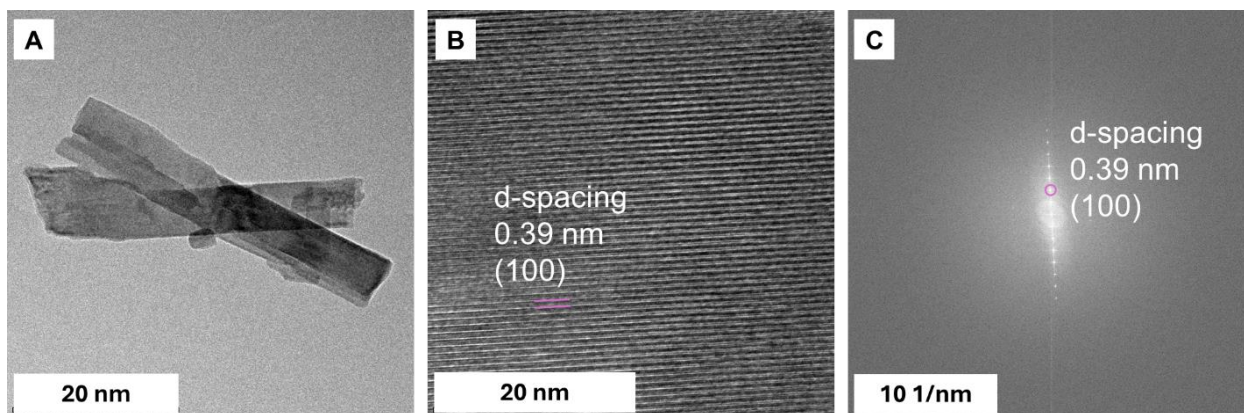


Figure S4. (A) TEM image of MnSb_2O_4 nanorods after treatment with a 1:1 molar ratio of XeF_2 in CH_3CN . (B) Lattice-resolved HRTEM image acquired for MnSb_2O_4 after treatment with a 1:1 molar ratio of XeF_2 indicating the separation between (100) planes. (C) Indexed SAED pattern acquired for indicating the (100) planes.

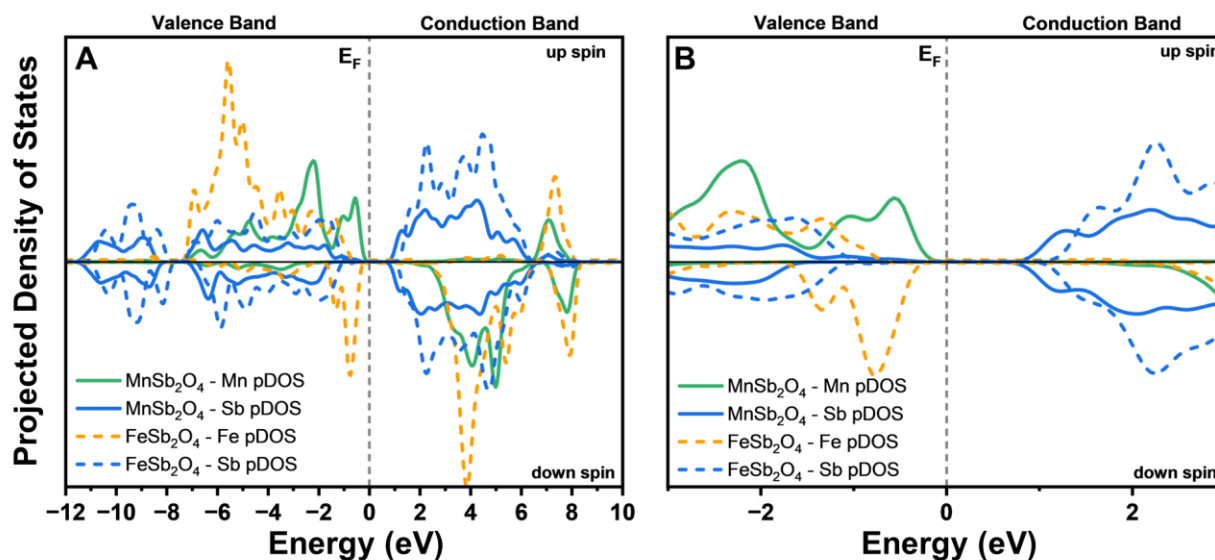


Figure S5. Comparison of transition metal and Sb projected density of states in FeSb_2O_4 and MnSb_2O_4 from (A) -12 to 10 eV and (B) -3 to 3 eV as a magnified view near the Fermi level.

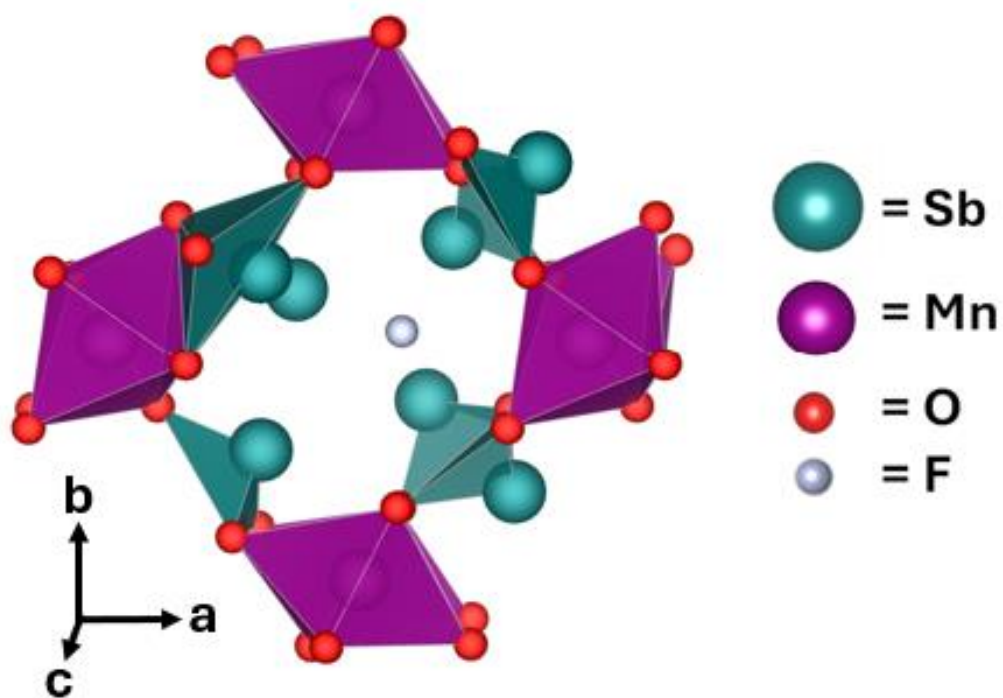


Figure S6. Putative optimized structure of $\text{MnSb}_2\text{O}_4\text{F}_x$ calculated via DFT methods seen along the crystallographic c direction.

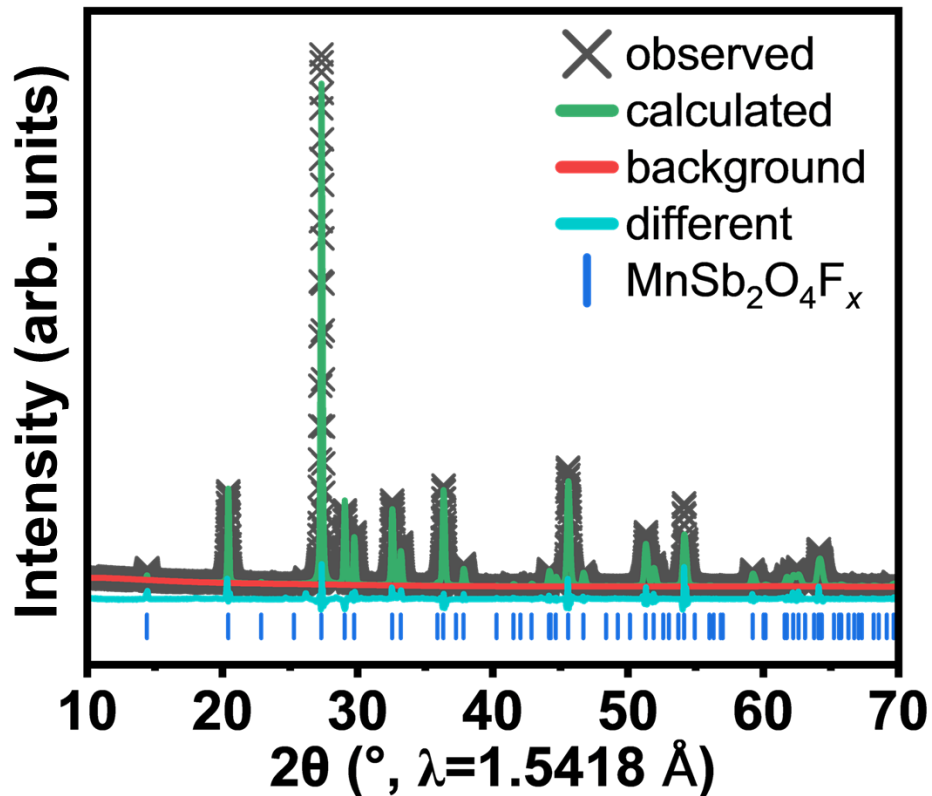


Figure S7. Rietveld refinement of powder diffraction data collected for MnSb_2O_4 after a 3 molar excess of NOBF_4 in CH_3CN . Refinement statistics, lattice parameters, and atom positions for the refinements of the reacted material are shown in Table S3.

Table S3. Atom positions, fractional occupancies, and thermal parameters obtained from Rietveld refinement of the powder XRD pattern acquired for MnSb_2O_4 after treatment with a 3 molar excess of NOBF_4 in CH_3CN . Refinement statistics and lattice parameters are included in the table header.

$a = b = 8.69488 \text{ \AA}$, $c = 6.00444 \text{ \AA}$ $\alpha = \beta = \gamma = 90^\circ$; Volume = 453.942 \AA^3 $\chi^2 = 64.497$; $R_{\text{wp}} = 16.698\%$; $\text{RF} = 11.803\%$					
Atom Label	Site Multiplicity	x	y	z	$U_{\text{iso}} * 100$
Mn	4	0.00	0.50	0.25	0.11(2)
Sb	8	0.1780(1)	0.1684(1)	0.00	0.01(0)
O(1)	8	0.0817(7)	0.6520(3)	0.00	0.22(5)
O(2)	8	0.6754(8)	0.1754(8)	0.25	2.84(1)
F	16	0.5273(5)	0.4961(7)	0.7404(2)	25

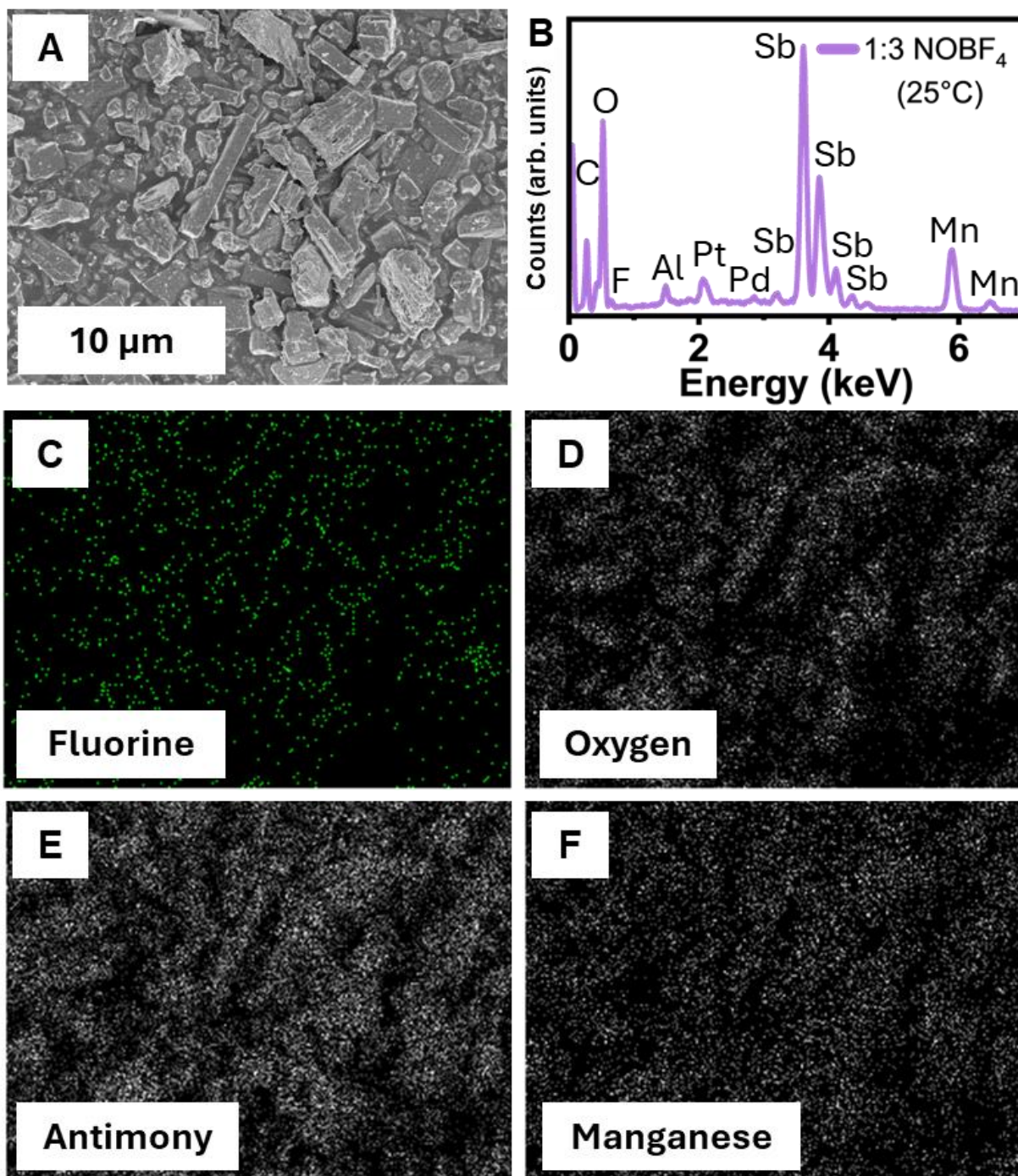


Figure S8. SEM-EDS images of 1:3 molar ratio of NOBF_4 in CH_3CN at 25 °C with (A) SEM image of as treated MnSb_2O_4 ; (B) EDS spectra; (C) fluorine elemental map; (D) oxygen elemental map; (E) antimony elemental map; and (G) manganese elemental map.

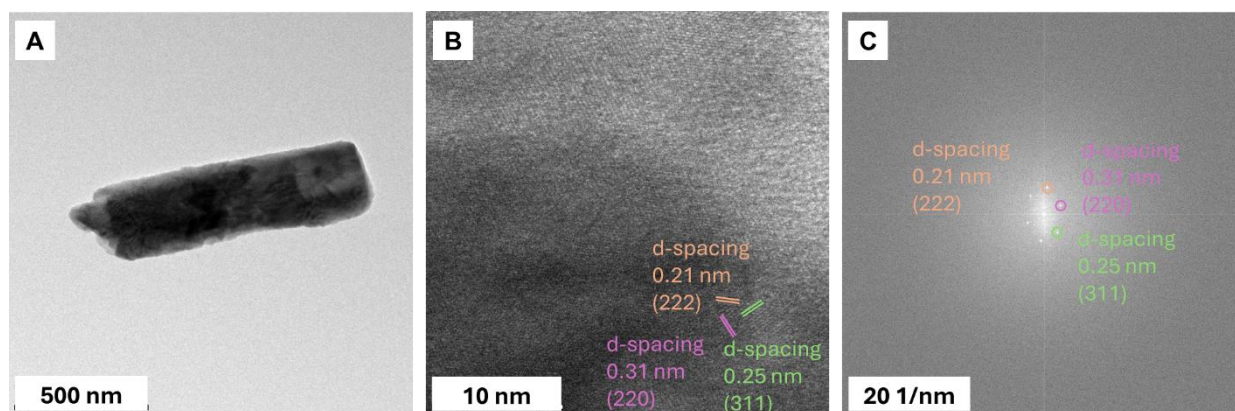


Figure S9. (A) TEM image of MnSb_2O_4 nanorods after treatment with a 3 molar excess of NOBF_4 in CH_3CN . (B) Lattice-resolved HRTEM image acquired for MnSb_2O_4 nanorods after treatment with a 3 molar excess of NOBF_4 in CH_3CN indicating the separation between (100), (220), and (311) planes. (C) Indexed SAED pattern acquired for indicating the (100), (220), and (311) planes.

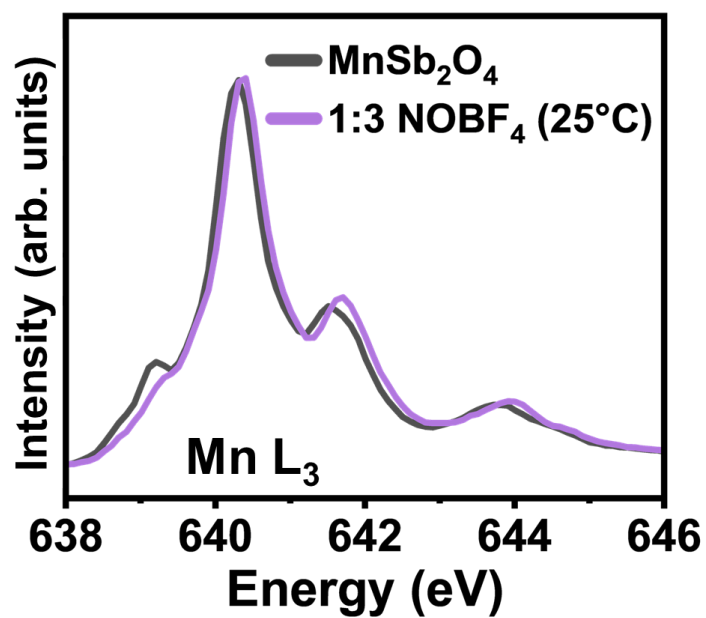


Figure S10. XANES Mn L_3 -edge spectra for pristine MnSb_2O_4 and after treatment with a 3 molar excess of NOBF_4 in CH_3CN .

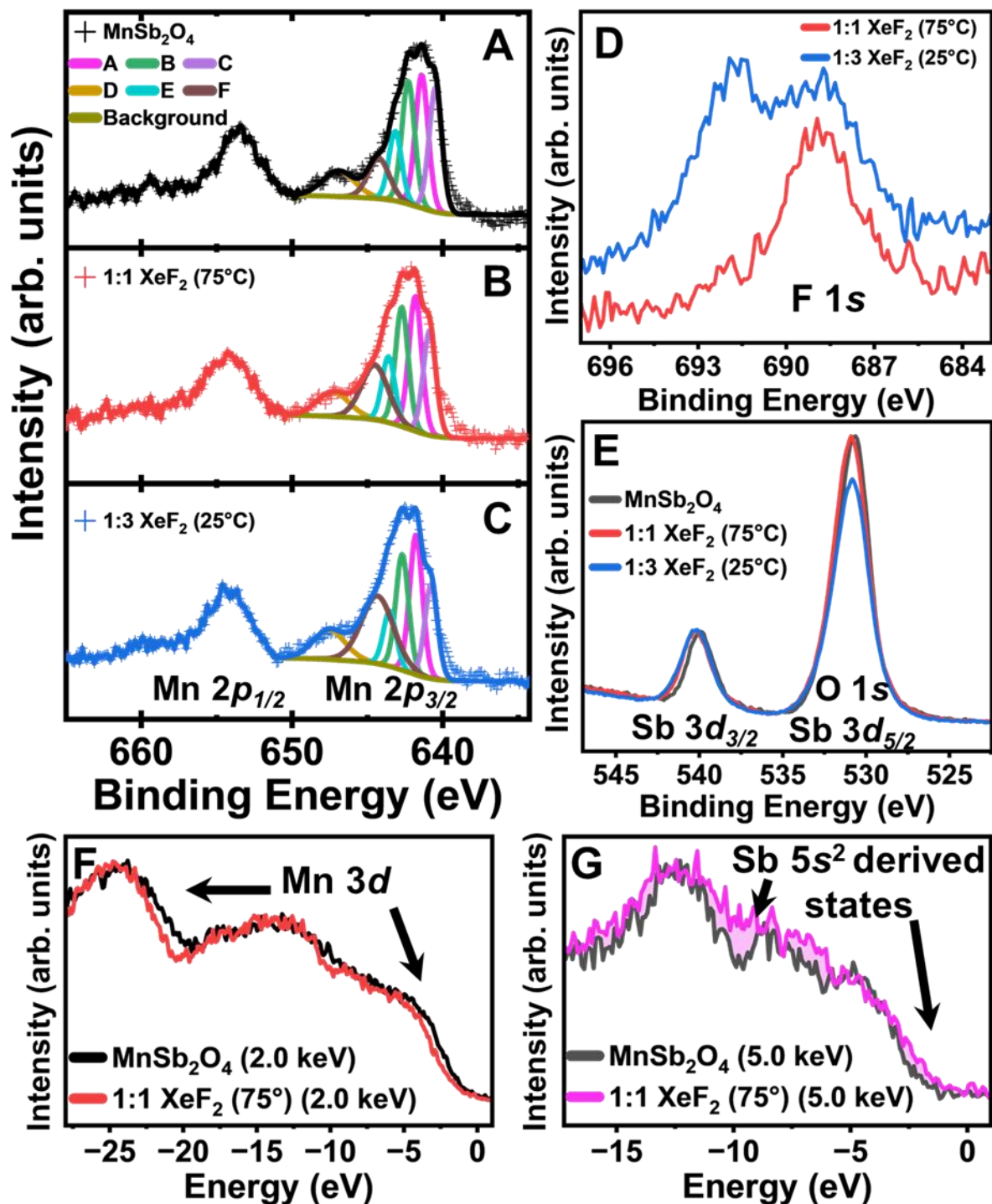
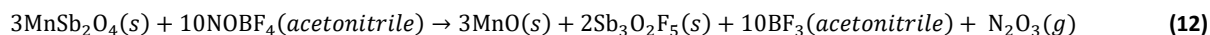
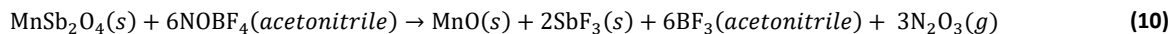
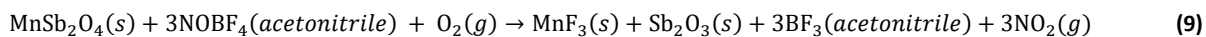
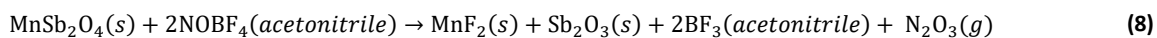
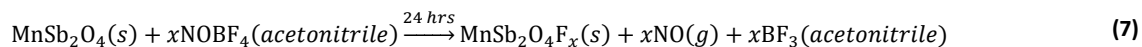
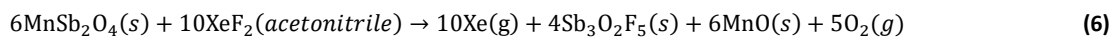
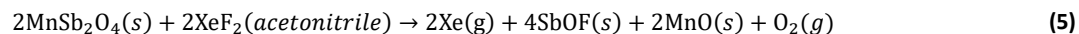
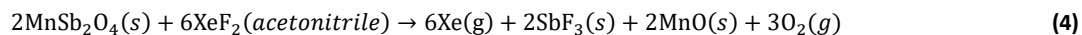
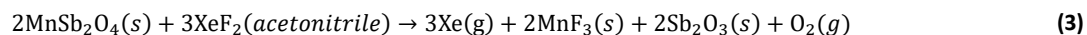
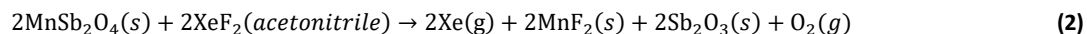
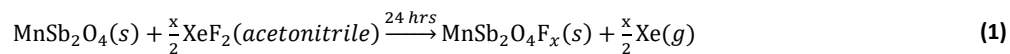


Figure S11. Fluoridation Products upon Reaction with NOBF₄. (A) XANES Sb M₄-edge and O K-edge spectra of as-prepared MnSb₂O₄ (gray) and after treatment with a 1:3 molar ratio of NOBF₄ (purple) in acetonitrile; (B) F-edge XANES spectra; (C) HAPXES F1s core level of MnSb₂O₄; (D) XPS spectra of MnSb₂O₄ (grey) and upon treatment with a 1:3 molar ratio of NOBF₄ (purple) in CH₃CN. Likely interphasic materials: (E) SbF₃, (F) SbOF, and (G) Sb₂O₃F₅.

Table S4. Possible reaction pathways for insertion and interphase formation: Products formed by the reaction of MnSb₂O₄ and XeF₂ in CH₃CN: (1) MnSb₂O₄F_x (Insertion), (2) formation of MnF₂, (3) formation of MnF₃, (4) formation of SbF₃, (5) formation of SbOF, and (6) formation of Sb₃O₂F₅. Products formed by the reaction of MnSb₂O₄ and NOBF₄ in CH₃CN: (7) MnSb₂O₄F_x (Insertion),

(8) formation of MnF₂, (9) formation of MnF₃, (10) formation of SbF₃, (11) formation of SbOF, and (12) formation of Sb₃O₂F₅. Each reaction was performed under flowing argon gas. Equation 9 depicts a potential interphase reaction; however, the balanced reaction requires oxygen gas as a reactant. Based on the greater density of argon gas versus oxygen gas, most likely oxygen was not present in the system. This reaction was included here for completeness.



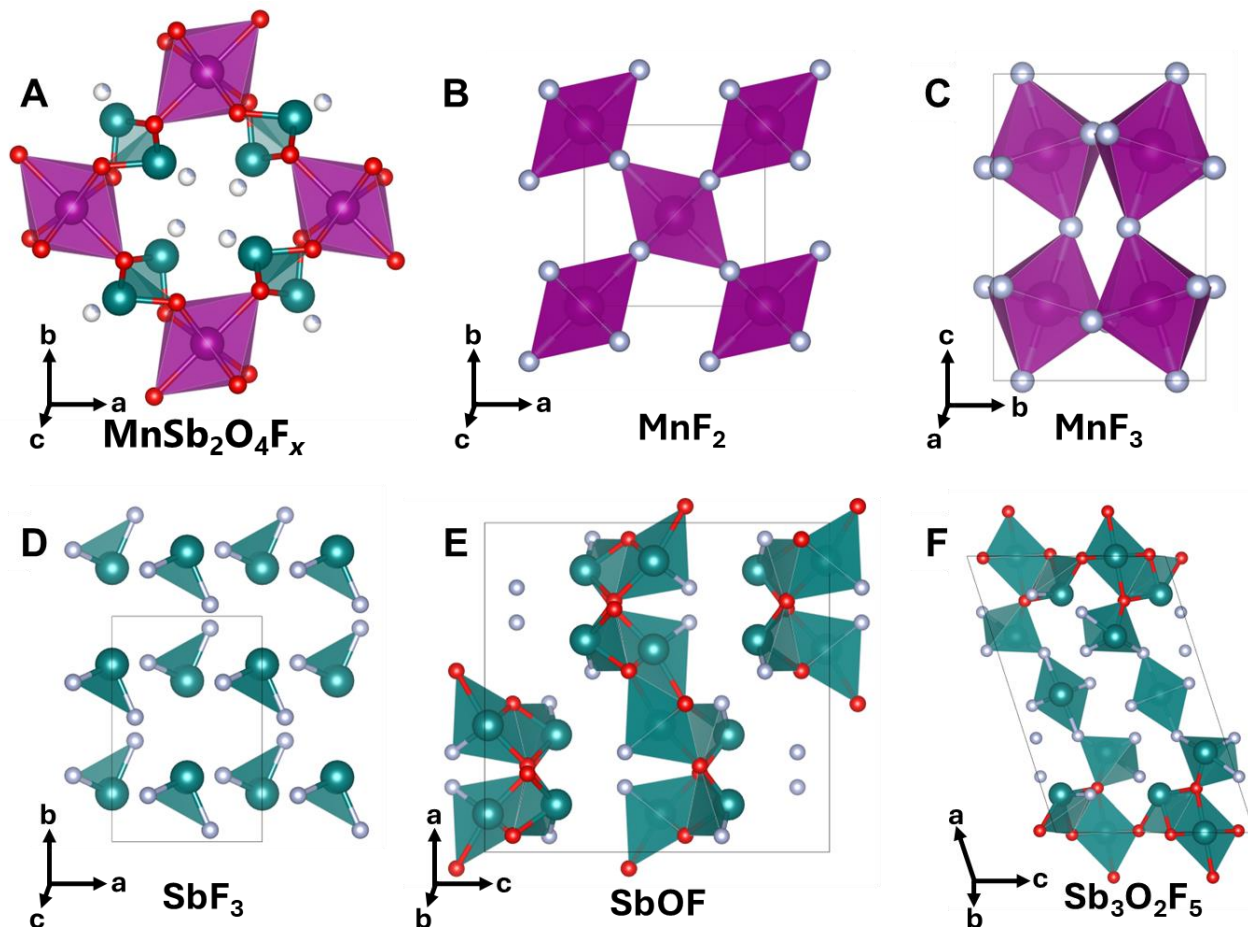


Figure S12. Potential reaction products after (A) insertion: $\text{MnSb}_2\text{O}_4\text{F}_x$; (B) manganese-based interphase formation: MnF_2 ; (C) manganese-based interphase formation: MnF_3 ; (D) antimony-based interphase formation: SbF_3 ; (E) antimony-based interphase formation: SbOF ; and (F) antimony-based interphase formation: $\text{Sb}_3\text{O}_2\text{F}_5$.

Materials and Method

Synthesis of MnSb_2O_4 particles: 4 mL of a 0.334 mol/L $\text{Mn}(\text{CH}_3\text{COO})_2 \cdot 4\text{H}_2\text{O}$ ($\geq 99.999\%$, VWR) aqueous solution was mixed with 4 mL of a 0.667 mol/L SbCl_3 ($\geq 99.0\%$, Millipore Sigma) aqueous solution prepared in 4 mol/L HCl (36.5% to 38.0%, Macron). The resulting mixture was titrated with 4 mL of an 8 mol/L aqueous solution of NaOH ($\geq 98\%$, Millipore Sigma) under constant stirring. The solution was then transferred to a polytetrafluoroethylene-lined high-temperature autoclave (Parr) and heated in a box furnace at $210\text{ }^\circ\text{C}$ for 48 h. The autoclave was removed from heating and allowed to cool to room temperature autogenously. The solid product was separated from the supernatant by centrifugation and was washed twice with deionized water (8500 rpm for 10 min – Thermo Scientific Heraeus Megafuge 8). The product was additionally washed (5 \times) by vortexing and then allowing the MnSb_2O_4 to settle (1–2 min) and decanted to remove the impurities based on density differences. A final centrifugation step was performed after dispersion in 2-propanol (VWR) (8500 rpm for 10 min). The product was dried at room temperature in air for 24 h and used without further modification for characterization and topochemical reactions.

Fluoridation of MnSb_2O_4 at $25\text{ }^\circ\text{C}$: Fluoridation reactions were performed in an argon-filled glovebox, maintained at O_2 and H_2O levels $< 0.1\text{ }\mu\text{L/L}$ and $0.1\text{ }\mu\text{L/L}$, respectively. A 35 mL aliquot of dry acetonitrile ($< 50\text{ }\mu\text{L/L}$ H_2O , Millipore Sigma) was added to a 100 mL round bottom flask. 100 mg of as-prepared MnSb_2O_4 was added to the flask along with a five-fold molar excess amount of XeF_2 (listed as 1:5 XeF_2) (99.5%, Thermo Fisher Scientific) at $25\text{ }^\circ\text{C}$. The mixture was stirred under argon for 24 h at $25\text{ }^\circ\text{C}$. The excess acetonitrile was decanted and the obtained product was washed three times with 10 mL acetonitrile (Fischer Scientific)

and once with 10 mL 2-propanol. The powder was dried at room temperature in air. Additional fluoridation reactions were completed with a one molar ratio and a three-fold molar excess.

Fluoridation reactions of MnSb_2O_4 at high temperature: High-temperature fluoridation reactions were refluxed in dry acetonitrile at 55 °C for 24 h on a Schlenk line under an flowing Ar gas. The washing and drying procedure was the same as described for the sample fluoridated at 25 °C. Additional high-temperature reactions were completed at 75 °C.

X-ray diffraction and structural characterization: Powder X-ray diffraction (XRD) patterns were collected in Bragg-Brentano geometry on a Bruker D8-focus diffractometer (Cu K- α , $\lambda = 1.5418 \text{ \AA}$; 40 kV voltage; 25 mA current). All Rietveld refinements were performed using the EXPGUI user interface of GSAS-II.¹ Atomic positions, profile terms, lattice parameters, and inserted fluorine occupancies were refined from the laboratory XRD data using isotropic thermal parameters. All crystal structure renditions were prepared using the Vesta III software suite (JP-Minerals).²

XANES measurements: XANES measurements in partial electron yield (PEY) mode were performed at beamline 7-ID-1 of the National Synchrotron Light Source II of Brookhaven National Laboratory operated by the National Institute of Standards and Technology. A detector entrance grid bias of -300 V was used to reduce the low-energy electrons and improve the surface sensitivity. A charge compensation gun was used to avert the charging of the samples. The data were collected with a resolution of 0.2 eV and ≈ 0.3 eV at the O K-edge; and Mn L-, F K- and Fe L-edges; respectively. The PEY signals were normalized to the incident beam intensity using the photocurrent from a freshly evaporated gold mesh. The spectra were energy calibrated to the O K-edge for a standard TiO_2 sample.

Mn and Sb K-edge XANES spectroscopy measurements were performed under atmospheric conditions at beamline 7-BM, a bending magnet beamline of the National Synchrotron Light Source II of Brookhaven National Laboratory. The X-ray photon energy was monochromatized using a silicon (III) channel-cut crystal monochromator operating in continuous scan mode. Samples were prepared by uniformly spreading powder onto a piece of polyetherimide tape affixed to a sample holder designed for use at beamline 7-BM. 30 scans were performed at 30 s per scan and averaged to improve the signal-to-noise ratio. For the edges collected, before data acquisition, the beamline was calibrated by placing the corresponding elemental foil and measuring the edge position. Both transmittance fluorescence yield data were acquired in each case. Athena from the IFEFFIT package was used for data sanitization.

Hard X-ray photoemission spectroscopy: HAXPES measurements were performed at the National Institute of Standards and Technology beamline SST-2 of National Synchrotron Light Source II of the Brookhaven National Laboratory. Measurements at an incident photon energy of 2 keV were performed with a pass energy of 200 eV, whereas the measurements at an incident photon energy of 5 keV were collected with a pass energy of 500 eV. The data were collected with a step size of 0.85 eV, and the analyzer axis was oriented parallel to the photoelectron polarization vector. The higher excitation energy of HAXPES circumvents deleterious charging issues that are common to ultraviolet and soft X-ray photoelectron spectroscopy. Photon energy selection was accomplished by using a double Si(111) crystal monochromator. The beam energy was aligned to the Fermi level of a silver foil before measurements.

Scanning electron microscopy: SEM images were collected using a JEOL JSM-7500F FE-instrument, an ultrahigh-resolution field-emission scanning electron microscope (FE-SEM) equipped with a high brightness conical FE gun and a low aberration conical objective lens. MnSb_2O_4 powder was spread on conductive carbon tape and sputter coated with platinum before imaging. Elemental maps were collected using the JEOL JSM-7500F FE-instrument equipped with a high-brightness conical field-emission gun, a low aberration conical objective lens, and an Oxford energy dispersive spectroscopy (EDS) system.

Transmission electron microscopy: High-resolution transmission electron microscopy (HRTEM) images and selected area electron diffraction (SAED) patterns were acquired using a FEI Tecnai G2 F20 field emission scanning electron microscope (FE-TEM) operated at 200 kV. Prior to imaging, the powder samples were dispersed in 2-propanol and drop-cast onto 300-mesh formvar-carbon films supported by copper grids (electron microscopy science). HRTEM images were analyzed using the Gatan Microscopy Suite software.

Density Functional Theory Calculations: Geometry optimizations were carried out using DFT as implemented in the Vienna Ab-initio Simulation Package (VASP) for MnSb_2O_4 .^{3,4} Brillouin zone integration was performed using a $4 \times 4 \times 2$ Monkhorst—Pack mesh.⁵ The projector-augmented wave formalism was used to capture electron—ion interactions. Electron exchange and correlation were

addressed using the generalized gradient approximation based on the Perdew-Burke-Ernzerhof functional (PAW-GGA-PBE).^{6–8} A Hubbard correction of $U = 5.0$ eV was used to account for strong electron correlation in the Mn 3d electrons as benchmarked in a previous study.⁹ Electronic self-consistent loop and ionic relaxation loops were adjusted to be below 10^{-5} and 10^{-4} eV, respectively.

A single-point energy calculation was performed to calculate the projected density of state (pDOS) with Local Orbital Suite Toward Electronic-Structure Reconstruction (LOBSTER).^{10,11} Bunge's description for the local basis functions were used for the pDOS calculation with 4s and 3d orbitals for manganese, 2s and 2p orbitals for oxygen, and 5s and 5p orbitals for antimony. The absolute charge spilling is lower than 1.26% in all cases.

Commercial names are mentioned in this paper to adequately specify the experimental procedure, and such specification is not intended to imply recommendation or endorsement by the National Institute of Standards and Technology.

Supporting References

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